

Agilent HSMP-382x, 482x Surface Mount RF PIN Switch and Limiter Diodes

Data Sheet

Description/Applications

The HSMP-382x series is optimized for switching applications where ultra-low resistance is required. The HSMP-482x diode is ideal for limiting and low inductance switching applications up to 1.5 GHz.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic, carrier lifetime.

Package Lead Code Identification, SOT-23 (Top View)











Package Lead Code Identification, SOT-323 (Top View)



Features

- Diodes Optimized for: Low Current Switching Low Distortion Attenuating
- Power Limiting/Circuit Protection
- Surface Mount SOT-23 and SOT-323 Packages
 Single and Dual Versions
 Tape and Reel Options
 Available
- Low Failure in Time (FIT)
 Rate^[1]
- Lead-free Option Available

Notes

 For more information see the Surface Mount PIN Reliability Data Sheet.

Absolute Maximum Ratings^[1] $T_C = +25^{\circ}C$

Symbol	Parameter	Unit	SOT-23	SOT-323
I_{f}	Forward Current (1 µs Pulse)	Amp	1	1
P _{IV}	Peak Inverse Voltage	V	50	50
$T_{\rm j}$	Junction Temperature	°C	150	150
T _{stg}	Storage Temperature	°C	-65 to 150	-65 to 150
θ_{jc}	Thermal Resistance ^[2]	°C/W	500	150

Notes

- Operation in excess of any one of these conditions may result in permanent damage to the device.
- 2. T_C = +25°C, where T_C is defined to be the temperature at the package pins where contact is made to the circuit board.

Electrical Specifications $T_{\rm C}$ = 25 $^{\circ}{\rm C}$

Part Number HSMP-	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	$\begin{array}{c} \textbf{Maximum} \\ \textbf{Series Resistance} \\ \textbf{R}_{\textbf{S}}\left(\Omega\right) \end{array}$	Maximum Total Capacitance C _T (pF)
3820	F0	0	Single	50	0.6	0.8
3822	F2	2	Series			
3823	F3	3	Common Anode			
3824	F4	4	Common Cathode			
Test Conditions			$V_R = V_{BR}$	f = 100 MHz	f = 1 MHz	
				Measure	$I_F = 10 \text{ mA}$	$V_{R} = 20 \text{ V}$
				$I_R \le 10 \mu A$		

High Frequency (Low Inductance, 500 MHz - 3 GHz) PIN Diodes

Part Number HSMP-	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	$\begin{array}{c} \textbf{Maximum} \\ \textbf{Series} \\ \textbf{Resistance} \\ \textbf{R}_{\textbf{S}}\left(\Omega\right) \end{array}$	Typical Total Capacitance C _T (pF)	$\begin{array}{c} \text{Maximum} \\ \text{Total} \\ \text{Capacitance} \\ \text{C}_{\text{T}}\left(\text{pF}\right) \end{array}$	Typical Total Inductance L _T (nH)
4820 482B	FA FA	A A	Dual Anode Dual Anode	50	0.6	0.75	1.0	1.0
Test Conditions			$\begin{aligned} V_R &= V_{BR} \\ Measure \\ I_R &\leq 10 \; \mu A \end{aligned}$	$I_{\rm F}$ = 10 mA	$\begin{aligned} \mathbf{f} &= 1 \text{ MHz} \\ \mathbf{V}_{\mathrm{R}} &= 20 \text{ V} \end{aligned}$	$\begin{aligned} \mathbf{f} &= 1 \text{ MHz} \\ \mathbf{V}_{\mathrm{R}} &= 0 \text{ V} \end{aligned}$	f = 500 MHz- 3 GHz	

Typical Parameters at $T_C = 25^{\circ}C$

Part Number HSMP-	Series Resistance $R_S(\Omega)$	Carrier Lifetime τ (ns)	Reverse Recovery Time T_{rr} (ns)	Total Capacitance C _T (pF)
382x	1.5	70	7	0.60 @ 20 V
Test Conditions	$\begin{aligned} f &= 100 \text{ MHz} \\ I_F &= 10 \text{ mA} \end{aligned}$	$I_{\mathrm{F}} = 10 \; \mathrm{mA}$	$\begin{array}{c} V_R = 10~V \\ I_F = 20~mA \\ 90\%~Recovery \end{array}$	

Typical Parameters at $T_C = 25$ °C (unless otherwise noted), Single Diode

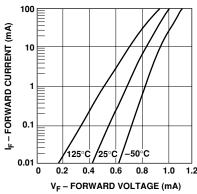


Figure 1. Forward Current vs. Forward Voltage.

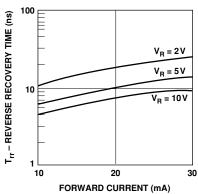


Figure 2. Reverse Recovery Time vs. Forward Current for Various Reverse Voltages.

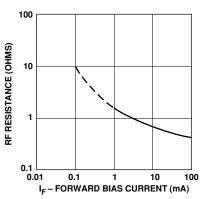


Figure 3. RF Resistance at 25°C vs. Forward Bias Current.

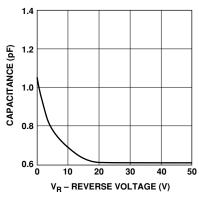


Figure 4. Capacitance vs. Reverse Voltage.

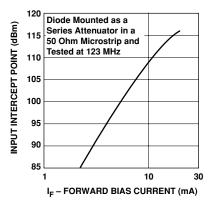


Figure 5. 2nd Harmonic Input Intercept Point vs. Forward Bias Current.

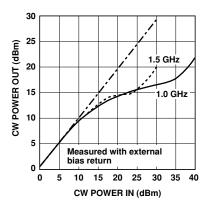


Figure 6. Large Signal Transfer Curve of the HSMP-482x Limiter.

Typical Applications for Multiple Diode Products

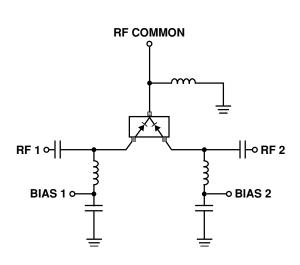


Figure 7. Simple SPDT Switch, Using Only Positive Current.

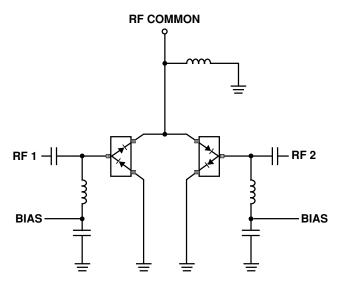


Figure 8. High Isolation SPDT Switch, Dual Bias.

Typical Applications for Multiple Diode Products, continued

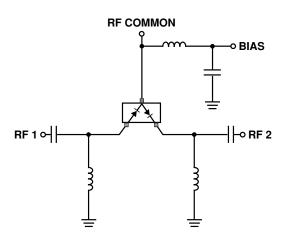
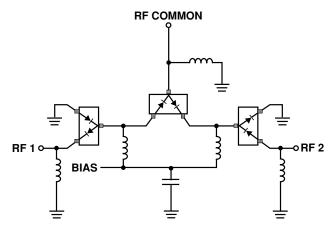


Figure 9. Switch Using Both Positive and Negative Bias Current.



 $\label{eq:Figure 10.Very High Isolation SPDT Switch, Dual Bias.}$

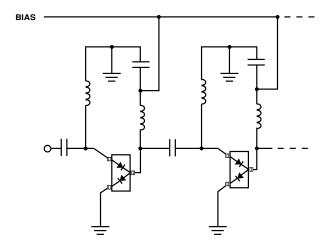


Figure 11. High Isolation SPST Switch (Repeat Cells as Required. $\,$

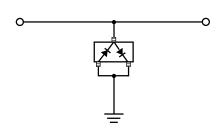


Figure 12. Power Limiter Using HSMP-3822 Diode Pair. See Application Note 1050 for details.

Typical Applications for HSMP-482x Low Inductance Series

Microstrip Series Connection for HSMP-482x Series

In order to take full advantage of the low inductance of the HSMP-482x series when using them in series applications, both lead 1 and lead 2 should be connected together, as shown in Figure 14.

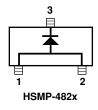


Figure 13. Internal Connections.

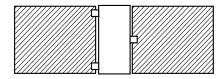


Figure 14. Circuit Layout.

Microstrip Shunt Connections for HSMP-482x Series

In Figure 15, the center conductor of the microstrip line is interrupted and leads 1 and 2 of the HSMP-482x diode are placed across the resulting gap. This forces the 0.5 nH lead inductance of leads 1 and 2 to appear as part of a low pass filter, reducing the shunt parasitic inductance and increasing the maximum available attenuation. The 0.3 nH of shunt inductance external to the diode is created by the via holes, and is a good estimate for 0.032" thick material.

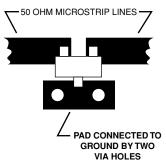


Figure 15. Circuit Layout, HSMP-482x Limiter.

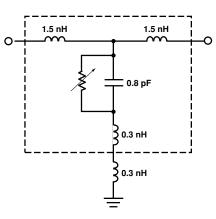


Figure 16. Equivalent Circuit.

Co-Planar Waveguide Shunt Connection for HSMP-482x Series

Co-Planar waveguide, with ground on the top side of the printed circuit board, is shown in Figure 17. Since it eliminates the need for via holes to ground, it offers lower shunt parasitic inductance and higher maximum attenuation when compared to a microstrip circuit. See AN1050 for details.

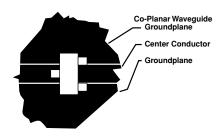


Figure 17. Circuit Layout.

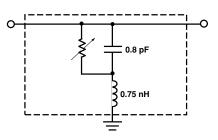


Figure 18. Equivalent Circuit.

Assembly Information SOT-323 PCB Footprint

A recommended PCB pad layout for the miniature SOT-323 (SC-70) package is shown in Figure 19 (dimensions are in inches). This layout provides ample allowance for package placement by automated assembly equipment without adding parasitics that could impair the performance.

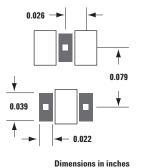


Figure 19. Recommended PCB Pad Layout for Agilent's SC70 3L/SOT-323 Products.

SOT-23 PCB Footprint

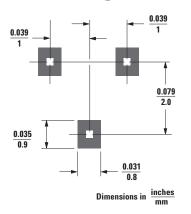


Figure 20. Recommended PCB Pad Layout for Agilent's SOT-23 Products.

SMT Assembly

Reliable assembly of surface mount components is a complex process that involves many material, process, and equipment factors, including: method of heating (e.g., IR or vapor phase reflow, wave soldering, etc.) circuit board material, conductor thickness and pattern, type of solder alloy, and the thermal conductivity and thermal mass of components. Components with a low mass, such as the SOT-323/-23 package, will reach solder reflow temperatures faster than those with a greater mass.

Agilent's diodes have been qualified to the time-temperature profile shown in Figure 21. This profile is representative of an IR reflow type of surface mount assembly process.

After ramping up from room temperature, the circuit board with components attached to it (held in place with solder paste) passes through one or more preheat zones. The preheat zones increase the temperature of the board and components to prevent thermal shock and begin evaporating solvents from the solder paste. The reflow zone briefly elevates the temperature sufficiently to produce a reflow of the solder.

The rates of change of temperature for the ramp-up and cooldown zones are chosen to be low enough to not cause deformation of the board or damage to components due to thermal shock. The maximum temperature in the reflow zone (T_{MAX}) should not exceed 235°C.

These parameters are typical for a surface mount assembly process for Agilent diodes. As a general guideline, the circuit board and components should be exposed only to the minimum temperatures and times necessary to achieve a uniform reflow of solder.

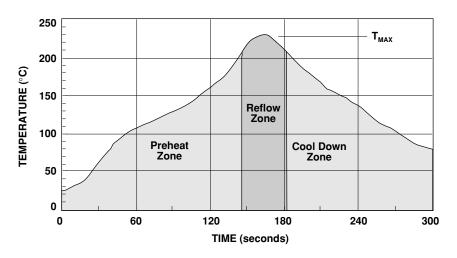
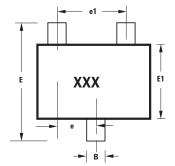
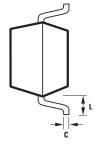
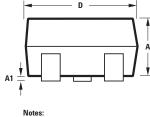


Figure 21. Surface Mount Assembly Profile.

Package Dimensions Outline SOT-323 (SC-70)



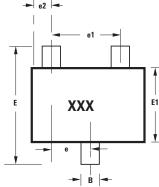


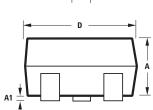


Notes:	
(XX-package marking	
Drawings are not to scale	

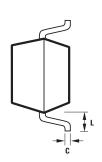
	DIMENSIONS (mm)				
SYMBOL	MIN.	MAX.			
Α	0.80	1.00			
A1	0.00	0.10			
В	0.15	0.40			
С	0.10	0.20			
D	1.80	2.25			
E1	1.10	1.40			
е	0.65 typical				
e1	1.30 typical				
E	1.80	2.40			
L	0.425 typical				

Outline 23 (SOT-23)





Notes:	
XXX-package marking	
Drawings are not to scal	e

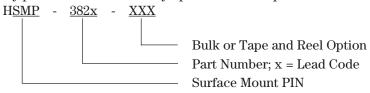


	DIMENSIONS (mm)		
SYMBOL	MIN.	MAX.	
Α	0.79	1.20	
A1	0.000	0.100	
В	0.37	0.54	
С	0.086	0.152	
D	2.73	3.13	
E1	1.15	1.50	
е	0.89	1.02	
e1	1.78	2.04	
e2	0.45	0.60	
E	2.10	2.70	
L	0.45	0.69	

Package Characteristics

Ordering Information

Specify part number followed by option. For example:



Option Descriptions

-BLK = Bulk, 100 pcs. per antistatic bag

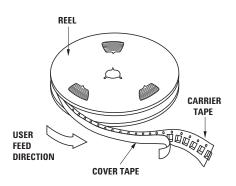
-TR1 = Tape and Reel, 3000 devices per 7" reel

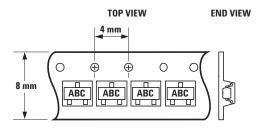
-TR2 = Tape and Reel, 10,000 devices per 13" reel

Tape and Reeling conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement."

For lead-free option, the part number will have the character "G" at the end, eg. -TR2G for a 10K pc lead-free reel.

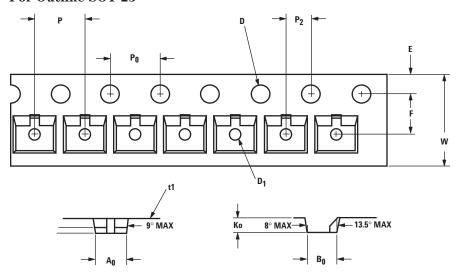
Device OrientationFor Outlines SOT-23/323





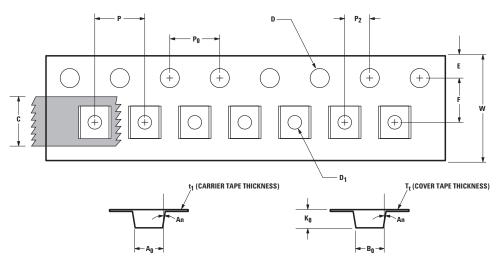
Note: "AB" represents package marking code.
"C" represents date code.

Tape Dimensions and Product Orientation For Outline SOT-23



	DESCRIPTION	SYMB0L	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	A ₀	3.15 ± 0.10	0.124 ± 0.004
	WIDTH	B ₀	2.77 ± 0.10	0.109 ± 0.004
	DEPTH	K ₀	1.22 ± 0.10	0.048 ± 0.004
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D ₁	1.00 + 0.05	$\textbf{0.039} \pm \textbf{0.002}$
PERFORATION	DIAMETER	D	1.50 + 0.10	0.059 + 0.004
	PITCH	P ₀	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	$\textbf{0.069} \pm \textbf{0.004}$
CARRIER TAPE	WIDTH	w	8.00 +0.30 -0.10	0.315+0.012-0.004
	THICKNESS	t1	0.229 ± 0.013	0.009 ± 0.0005
DISTANCE BETWEEN	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
CENTERLINE	CAVITY TO PERFORATION (LENGTH DIRECTION)	P ₂	$\textbf{2.00} \pm \textbf{0.05}$	$\textbf{0.079} \pm \textbf{0.002}$

Tape Dimensions and Product Orientation For Outline SOT-323



	DESCRIPTION	SYMB0L	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH WIDTH DEPTH PITCH BOTTOM HOLE DIAMETER	A ₀ B ₀ K ₀ P D ₁	2.40 ± 0.10 2.40 ± 0.10 1.20 ± 0.10 4.00 ± 0.10 1.00 + 0.25	0.094 ± 0.004 0.094 ± 0.004 0.047 ± 0.004 0.157 ± 0.004 0.039 + 0.010
PERFORATION	DIAMETER PITCH POSITION	D P ₀ E	1.55 ± 0.05 4.00 ± 0.10 1.75 ± 0.10	$\begin{array}{c} 0.061 \pm 0.002 \\ 0.157 \pm 0.004 \\ 0.069 \pm 0.004 \end{array}$
CARRIER TAPE	WIDTH THICKNESS	W t ₁	8.00 ± 0.30 0.254 ± 0.02	$\begin{array}{c} 0.315 \pm 0.012 \\ 0.0100 \pm 0.0008 \end{array}$
COVER TAPE	WIDTH TAPE THICKNESS	C T _t	5.4 ± 0.10 0.062 ± 0.001	$\begin{array}{c} 0.205 \pm 0.004 \\ 0.0025 \pm 0.00004 \end{array}$
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION) CAVITY TO PERFORATION (LENGTH DIRECTION)	F P ₂	3.50 ± 0.05 2.00 ± 0.05	0.138 ± 0.002 0.079 ± 0.002
ANGLE	FOR SOT-323 (SC70-3 LEAD) FOR SOT-363 (SC70-6 LEAD)	An	8°C MAX 10°C MAX	

www.agilent.com/semiconductors

For product information and a complete list of distributors, please go to our web site.

For technical assistance call:

Americas/Canada: +1 (800) 235-0312 or

(916) 788-6763

Europe: +49 (0) 6441 92460 China: 10800 650 0017 Hong Kong: (+65) 6756 2394

India, Australia, New Zealand: (+65) 6755 1939 Japan: (+81 3) 3335-8152(Domestic/International), or

0120-61-1280(Domestic Only) Korea: (65) 6755 1989

Singapore, Malaysia, Vietnam, Thailand, Philippines, Indonesia: (65) 6755 2044

Taiwan: (65) 6755 1843

Data subject to change.

Copyright © 2005 Agilent Technologies, Inc.

Obsoletes 5989-2498EN September 28, 2005 5989-4026EN

